

50 MHz to 6000 MHz InGaP HBT ACTIVE BIAS GAIN BLOCK

Package Style: Hermetic, 2-pin, 5.8mmx2.8mm





Features

Single Fixed 5V Supply

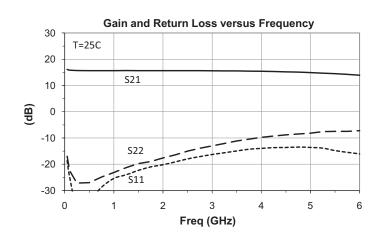
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- Patented Self Bias Circuit and Thermal Design
- Hermetic Package for High-Reliability Applications
- OIP3=38dBm at 1150MHz
- PIdB=19dBm at 1150MHz

Applications

- Military and Space Communications.
- Industrial Applications
- Aerospace and Defense



Product Description

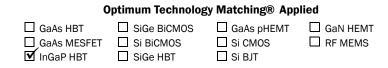
RFMD's SBB-4082S is a high-performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network in a hermetic package. The active bias network provides stable current over temperature and Beta process variations. The SBB-4082S is designed for high linearity gain block military and industrial applications requiring excellent gain flatness, small size, minimal external components and hermetic packaging. RFMD can provide various levels of device screening for military or high-reliability space applications.

Ordering Information

SBB-4082S

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Hermetic Package



S Thorr sive Road, Greer sb ro, NC 27409-04211 or sales te unita ort, contact REMD at (+ 1) 336'678-5570 realer≼uypor@\fn d.corr

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Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I _D)	100	mA
Max Device Voltage (V _D)	5.5	V
Max RF Input Power	+24	dBm
Max Junction Temperature (T _J)	+150	°C
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-55 to +150	°C
ESD - Human Body Model (HBM)	Class 1C	
MSL - Moisture Sensitivity Level	Hermetic	

Caution! ESD sensitive device.

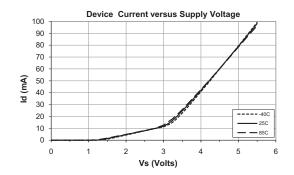
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Parameter	Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition
Small Signal Gain	14	15.5	18	dB	1000MHz to 1300MHz
		15		dB	4GHz
Output Power at 1dB Compression	18	19	22	dBm	1150MHz
OIP ₃	33	38		dBm	F1=1150MHz, F2=1151MHz
Input Return Loss	11	20		dB	1000MHz to 1300MHz
		14		dB	4GHz
Output Return Loss	10	20		dB	1000MHz to 1300MHz
		10		dB	4 GHz
Reverse Isolation	17	18.5		dB	1000 MHz to 1300 MHz
Noise Figure		4.5	6.0	dB	1150MHz
Operating Voltage		5.0		V	
Operating Current	58	80	92.0	mA	
Thermal Resistance		87		C/W	Junction to Lead

Test Conditions: $V_D=5V$ $I_D=80$ mA Typ. OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=5dBm, $T_L=25^{\circ}$ C, $Z_S=Z_L=50\Omega$, Tested with Bias Tees

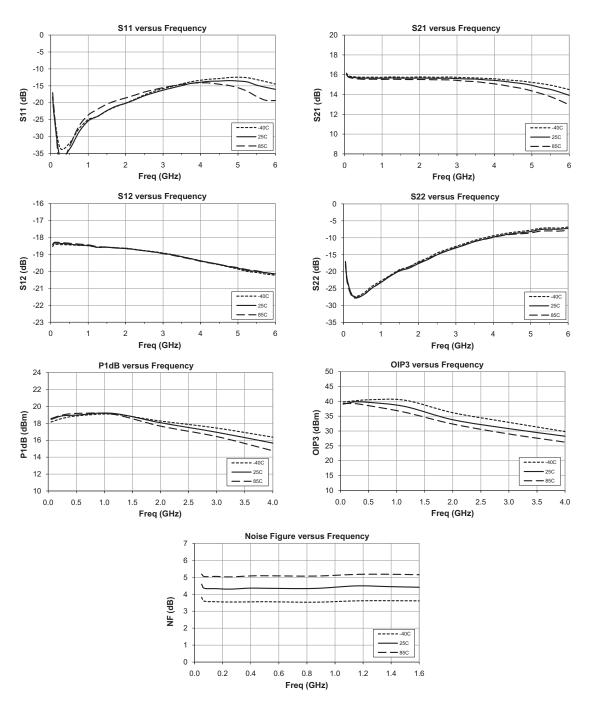






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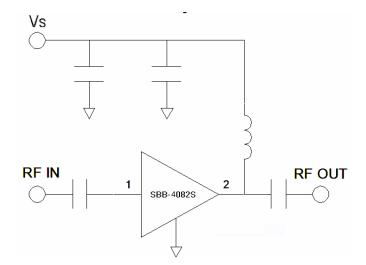
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Typical Application Schematic

Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external blocking capacitor chosen for the frequency of operation.
2	RF OUT/DC Bias	RF output and bias pin. This pin requires the use of an external blocking capacitor chosen for the frequency of operation.
Package Paddle	GND	Package backside must be connected to RF/DC ground.





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Package Drawing

